

isc N-Channel MOSFET Transistor

IXTY2R4N50P

• FEATURES

- Static drain-source on-resistance:
 $R_{DS(on)} \leq 3.75\Omega @ V_{GS}=10V$
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATION

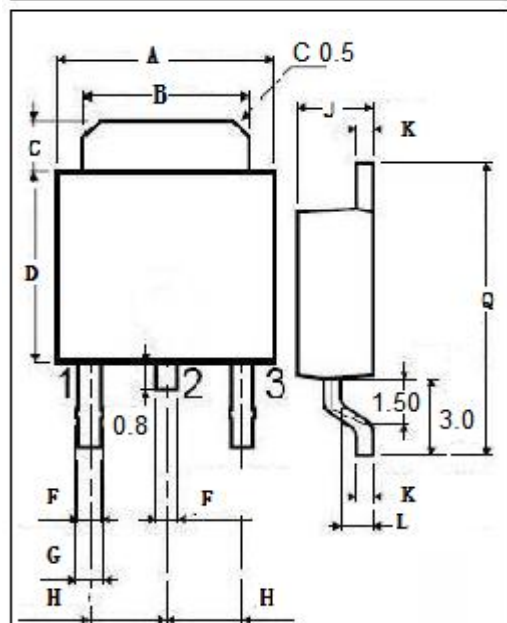
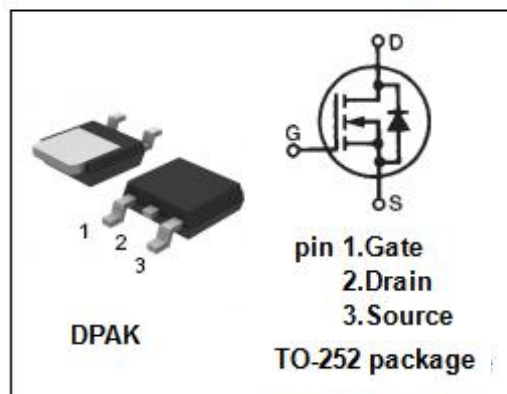
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DS}	Drain-Source Voltage	500	V
V_{GS}	Gate-Source Voltage	± 30	V
I_D	Drain Current-Continuous	2.4	A
I_{DM}	Drain Current-Single Pulsed	4.5	A
P_D	Total Dissipation @ $T_c=25^\circ\text{C}$	55	W
T_j	Operating Junction Temperature	-55~150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~150	$^\circ\text{C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Junction-to-case thermal resistance	2.27	$^\circ\text{C/W}$



DIM	mm	
	MIN	MAX
A	6.40	6.60
B	5.20	5.40
C	1.15	1.35
D	5.70	6.10
F	0.65	
G	0.75	
H	2.10	2.50
J	2.10	2.40
K	0.40	0.60
L	0.90	1.10
Q	9.90	10.1

isc N-Channel MOSFET Transistor**IXTY2R4N50P****ELECTRICAL CHARACTERISTICS** $T_c=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V$; $I_D=250\ \mu A$	500		V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$; $I_D=250\ \mu A$	3.0	5.5	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10V$; $I_D=1.2A$		3.75	Ω
I_{GSS}	Gate-Source Leakage Current	$V_{GS}=\pm 30V$; $V_{DS}=0V$		± 50	nA
I_{DSS}	Drain-Source Leakage Current	$V_{DS}=V_{DSS}$; $V_{GS}=0V$		1	μA
		$V_{DS}=V_{DSS}$; $V_{GS}=0V$; $T_J=125^{\circ}\text{C}$		50	
V_{SD}	Diode forward voltage	$I_F=2.4A$; $V_{GS}=0V$		1.5	V

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